

RELIABILITY REPORT
FOR
MAX4372FEUK+T
PLASTIC ENCAPSULATED DEVICES

February 15, 2013

MAXIM INTEGRATED

160 RIO ROBLES
SAN JOSE, CA 95134

Approved by
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Conclusion

The MAX4372FEUK+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX4372 low-cost, precision, high-side current-sense amplifier is available in a tiny, space-saving SOT23-5-pin package. Offered in three gain versions (T = 20V/V, F = 50V/V, and H = 100V/V), this device operates from a single 2.7V to 28V supply and consumes only 30 μ A. It features a voltage output that eliminates the need for gain-setting resistors and is ideal for today's notebook computers, cell phones, and other systems where battery/DC current monitoring is critical. High-side current monitoring is especially useful in battery-powered systems since it does not interfere with the ground path of the battery charger. The input common-mode range of 0 to 28V is independent of the supply voltage and ensures that the current-sense feedback remains viable even when connected to a 2-cell battery pack in deep discharge. The user can set the full-scale current reading by choosing the device (T, F, or H) with the desired voltage gain and selecting the appropriate external sense resistor. This capability offers a high level of integration and flexibility, resulting in a simple and compact current-sense solution. For higher bandwidth applications, refer to the MAX4173T/F/H data sheet.

II. Manufacturing Information

A. Description/Function:	Low-Cost, UCSP/SOT23, Micropower, High-Side Current-Sense Amplifier with Voltage Output
B. Process:	B12
C. Number of Device Transistors:	226
D. Fabrication Location:	Oregon, California or Texas
E. Assembly Location:	Malaysia, Thailand
F. Date of Initial Production:	October 21, 1999

III. Packaging Information

A. Package Type:	5-pin SOT23
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Non-conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-2243
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	324.3°C/W
K. Single Layer Theta Jc:	82°C/W
L. Multi Layer Theta Ja:	255.9°C/W
M. Multi Layer Theta Jc:	81°C/W

IV. Die Information

A. Dimensions:	57X38 mils
B. Passivation:	Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	1.2 microns (as drawn)
F. Minimum Metal Spacing:	1.2 microns (as drawn)
G. Bondpad Dimensions:	
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

- A. Quality Assurance Contacts: Richard Aburano (Manager, Reliability Engineering)
Don Lipps (Manager, Reliability Engineering)
Bryan Preeshl (Vice President of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{1000 \times 4340 \times 160 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 1.3 \times 10^{-9}$$

$$\lambda = 1.3 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maximintegrated.com/qa/reliability/monitor>. Cumulative monitor data for the B12 Process results in a FIT Rate of 0.06 @ 25C and 1.06 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot JAEF8A026A D/C 1217)

The OP85-1 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA and overvoltage per JEDEC JESD78.

Table 1
Reliability Evaluation Test Results

MAX4372FEUK+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test (Note 1)	Ta = 135°C	DC Parameters	80	0	N2ABD2169C, D/C 1018
	Biased	& functionality	80	0	N2ACD2166B, D/C 0950
	Time = 1000 hrs.				

Note 1: Life Test Data may represent plastic DIP qualification lots.